



## MMIC VCO w/ HALF FREQUENCY OUTPUT 7.8 - 8.8 GHz

### Typical Applications

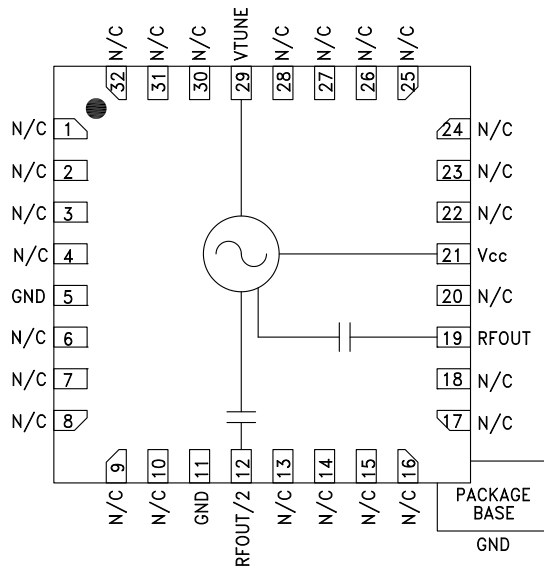
Low noise MMIC VCO w/Half Frequency, for:

- VSAT Radio
- Point to Point/Multi-Point Radio
- Test Equipment & Industrial Controls
- Military End-Use

### Features

- Dual Output:  $F_o = 7.8 - 8.8 \text{ GHz}$   
 $F_o/2 = 3.9 - 4.4 \text{ GHz}$
- Pout: +13 dBm
- Phase Noise: -115 dBc/Hz @100 kHz Typ.
- No External Resonator Needed
- 32 Lead 5x5mm SMT Package: 25mm<sup>2</sup>

### Functional Diagram



### General Description

The HMC509LP5 & HMC509LP5E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs. The HMC509LP5 & HMC509LP5E integrate resonators, negative resistance devices, varactor diodes and feature a half frequency output. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +13 dBm typical from a +5V supply. The voltage controlled oscillator is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

### Electrical Specifications, $T_A = +25^\circ \text{C}$ , $V_{cc} = +5V$

Parameter	Min.	Typ.	Max.	Units
Frequency Range		7.8 - 8.8		GHz
		3.9 - 4.4		GHz
Power Output	+10		+15	dBm
	+5		+10	dBm
SSB Phase Noise @ 100 kHz Offset, $V_{tune} = +5V$ @ RFOUT		-115		dBc/Hz
Tune Voltage	2		13	V
Supply Current ( $I_{cc}$ ) ( $V_{cc} = +5.0V$ )	200	250	270	mA
Tune Port Leakage Current ( $V_{tune} = 13V$ )			10	$\mu A$
Output Return Loss		2		dB
Harmonics/Subharmonics				
	1/2	35		dBc
	2nd	10		dBc
	3rd	32		dBc
Pulling (into a 2.0:1 VSWR)		5		MHz pp
Pushing @ $V_{tune} = 5V$		10		MHz/V
Frequency Drift Rate		0.9		MHz/ $^\circ C$

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# HMC509\* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

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## COMPARABLE PARTS

View a parametric search of comparable parts.

## EVALUATION KITS

- HMC509LP5 Evaluation Board.

## DOCUMENTATION

### Data Sheet

- HMC509 Data Sheet

## REFERENCE MATERIALS

### Quality Documentation

- Package/Assembly Qualification Test Report: 32L 5x5mm QFN Package (QTR: 10009 REV: 05)
- Package/Assembly Qualification Test Report: LP3, LP4, LP5 & LP5G (QTR: 2014-00145)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

### Technical Articles

- High Performance SiGe PLLs Pair with Low Phase Noise GaAs VCOs for Microwave Radio

## DESIGN RESOURCES

- HMC509 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

## DISCUSSIONS

View all HMC509 EngineerZone Discussions.

## SAMPLE AND BUY

Visit the product page to see pricing options.

## TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

## DOCUMENT FEEDBACK

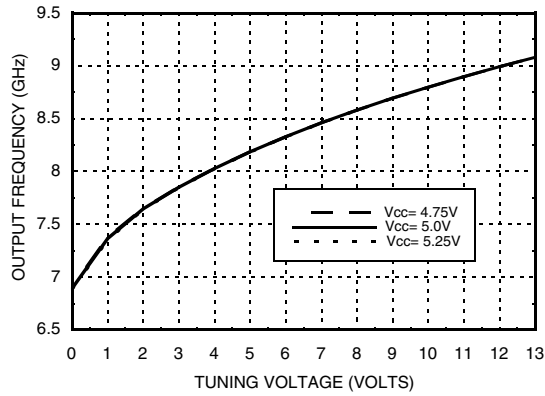
Submit feedback for this data sheet.



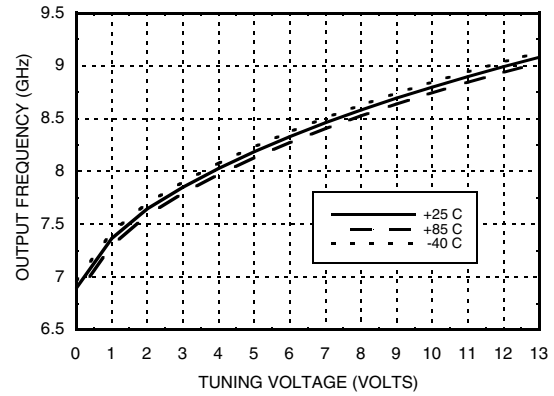
**HMC509LP5 / 509LP5E**

**MMIC VCO w/ HALF FREQUENCY OUTPUT 7.8 - 8.8 GHz**

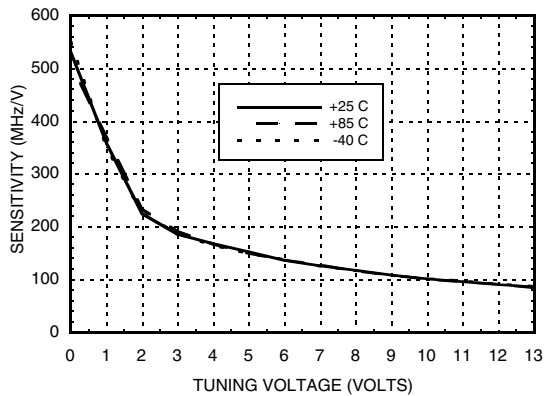
**Frequency vs. Tuning Voltage, T= 25°C**



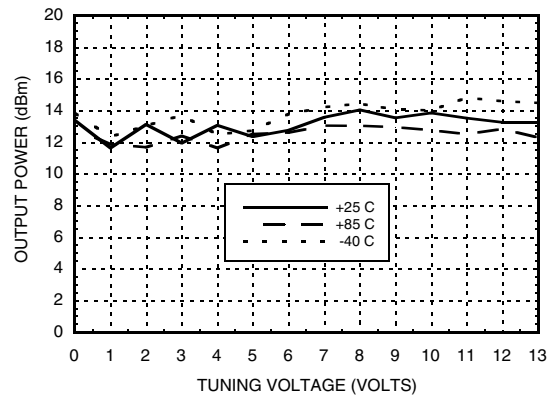
**Frequency vs. Tuning Voltage, Vcc= +5V**



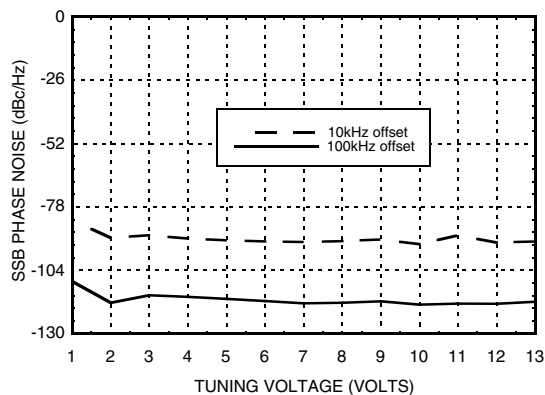
**Sensitivity vs. Tuning Voltage, Vcc= +5V**



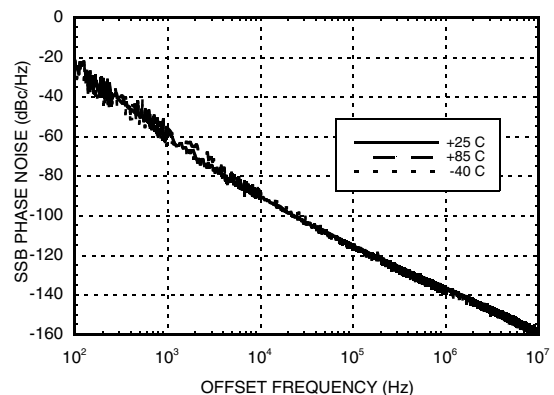
**Output Power vs. Tuning Voltage, Vcc= +5V**



**SSB Phase Noise vs. Tuning Voltage**



**SSB Phase Noise @ Vtune = +5V**



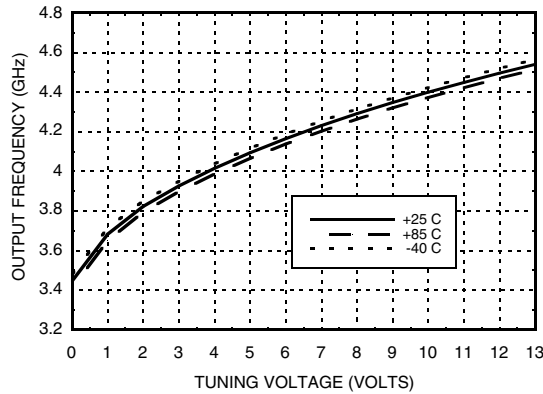
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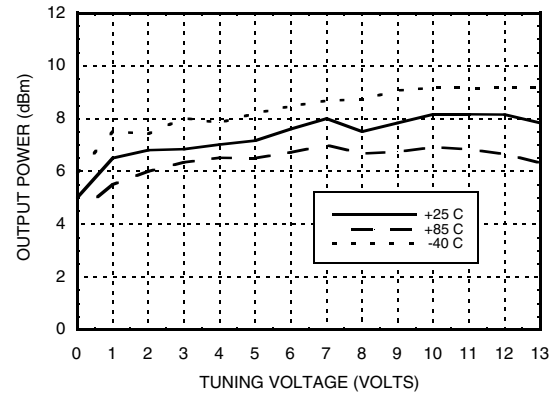


## MMIC VCO w/ HALF FREQUENCY OUTPUT 7.8 - 8.8 GHz

**RFOUT/2 Frequency  
vs. Tuning Voltage, Vcc= +5V**



**RFOUT/2 Output Power  
vs. Tuning Voltage, Vcc= +5V**



### Absolute Maximum Ratings

Vcc	+5.5 Vdc
Vtune	0 to +15V
Junction Temperature	135 °C
Continuous Pdiss (T=85 °C) (derate 26.7 mW/C above 85 °C)	1.34 W
Thermal Resistance (junction to ground paddle)	37.3 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

### Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)
4.75	210
5.0	250
5.25	270

Note: VCO will operate over full voltage range shown above.

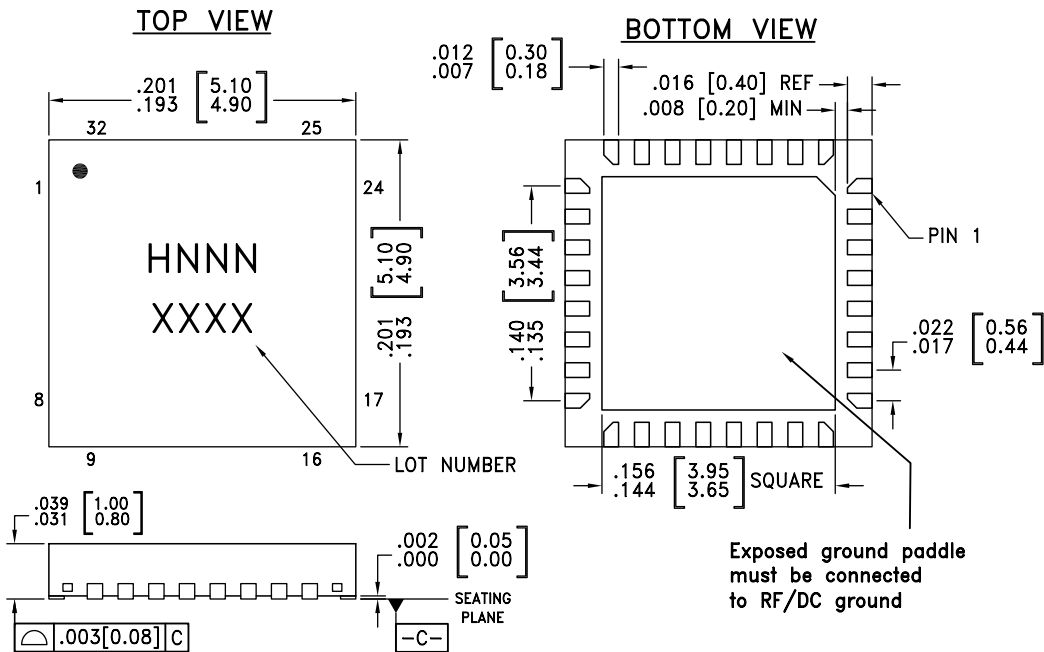


**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**



## MMIC VCO w/ HALF FREQUENCY OUTPUT 7.8 - 8.8 GHz

### Outline Drawing



- NOTES:
1. LEADFRAME MATERIAL: COPPER ALLOY
  2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
  3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
  4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.  
PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
  5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
  6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
  7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[3]</sup>
HMC509LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL3 <sup>[1]</sup>	H509 XXXX
HMC509LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 <sup>[2]</sup>	H509 XXXX

[1] Max peak reflow temperature of 235 °C  
 [2] Max peak reflow temperature of 260 °C  
 [3] 4-Digit lot number XXXX



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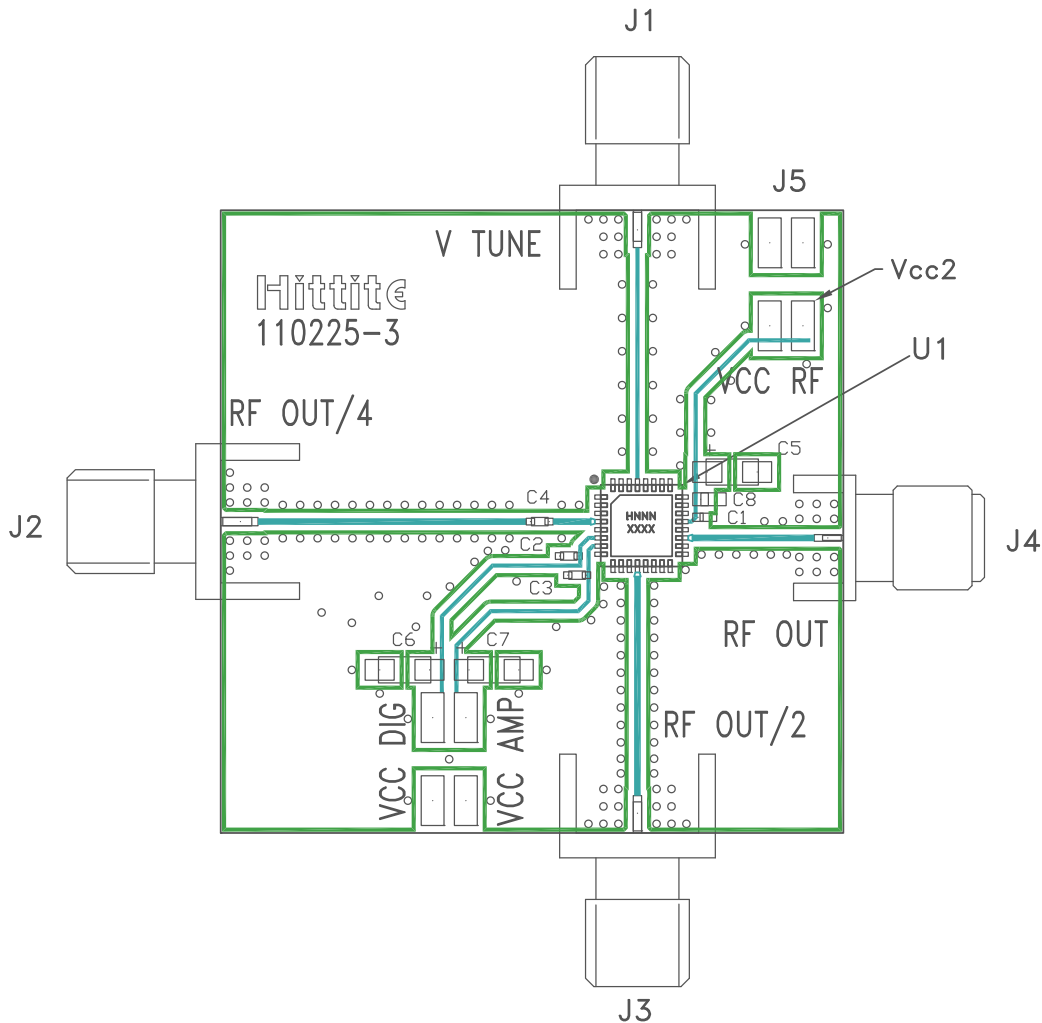
### Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1 - 4, 6 - 10, 13 - 18, 20, 22 - 28, 30 - 32	N/C	No Connection. These pins may be connected to RF/DC ground. Performance will not be affected.	
12	RFOUT/2	Half frequency output (AC coupled).	
19	RFOUT	RF output (AC coupled).	
21	Vcc	Supply Voltage, +5V	
29	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	
5, 11, Paddle	GND	Package bottom has an exposed metal paddle that must be connected to RF/DC ground.	



**MMIC VCO w/ HALF FREQUENCY  
OUTPUT 7.8 - 8.8 GHz**

**Evaluation PCB**



**List of Materials for Evaluation PCB 110227 [1]**

Item	Description
J1 - J4	PCB Mount SMA RF Connector
J5	2 mm DC Header
C1 - C3	100 pF Capacitor, 0402 Pkg.
C4	1,000 pF Capacitor, 0402 Pkg.
C5 - C7	2.2 $\mu$ F Tantalum Capacitor
U1	HMC509LP5(E) VCO
PCB [2]	110225 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and backside ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.